



# PMV100ENE

30 V, N-channel Trench MOSFET

17 March 2016

Product data sheet

## 1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

## 2. Features and benefits

- Logic level compatible
- Very fast switching
- Trench MOSFET technology
- ElectroStatic Discharge (ESD) protection > 2 kV HBM
- AEC-Q101 qualified

## 3. Applications

- Relay driver
- High-speed line driver
- Low-side loadswitch
- Switching circuits

## 4. Quick reference data

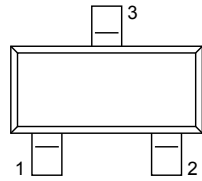
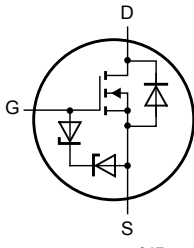
Table 1. Quick reference data

| Symbol                        | Parameter                        | Conditions   | Min | Typ | Max | Unit       |
|-------------------------------|----------------------------------|--|-----|-----|-----|------------|
| $V_{DS}$                      | drain-source voltage             | $T_j = 25\text{ °C}$   | -   | -   | 30  | V          |
| $V_{GS}$                      | gate-source voltage              |  | -20 | -   | 20  | V          |
| $I_D$                         | drain current                    | $V_{GS} = 10\text{ V}; T_{amb} = 25\text{ °C}$               | [1] | -   | 3   | A          |
| <b>Static characteristics</b> |                                  |  |     |     |     |            |
| $R_{DSon}$                    | drain-source on-state resistance | $V_{GS} = 10\text{ V}; I_D = 3\text{ A}; T_j = 25\text{ °C}$ | -   | 54  | 72  | m $\Omega$ |

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm<sup>2</sup>.

## 5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline  | Graphic symbol   |
|-----|--------|-------------|---|--|
| 1   | G      | gate        |  <p>TO-236AB (SOT23)</p> |  <p>017aaa255</p> |
| 2   | S      | source      |   |  |
| 3   | D      | drain       |   |  |

## 6. Ordering information

Table 3. Ordering information

| Type number | Package  |  |         |
|-------------|----------|--|---------|
|             | Name     | Description                              | Version |
| PMV100ENEA  | TO-236AB | plastic surface-mounted package; 3 leads | SOT23   |

## 7. Marking

Table 4. Marking codes

| Type number | Marking code |
|-------------|--------------|
| PMV100ENEA  | DW%<br>[1]   |

[1] % = placeholder for manufacturing site code

## 8. Limiting values

**Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol                    | Parameter                                    | Conditions  |     | Min | Max  | Unit |
|---------------------------|--|---|-----|-----|------|------|
| $V_{DS}$                  | drain-source voltage                         | $T_j = 25\text{ °C}$  |     | -   | 30   | V    |
| $V_{GS}$                  | gate-source voltage                          |   |     | -20 | 20   | V    |
| $I_D$                     | drain current                                | $V_{GS} = 10\text{ V}; T_{amb} = 25\text{ °C}$  | [1] | -   | 3    | A    |
| $I_{DM}$                  | peak drain current                           | $T_{amb} = 25\text{ °C};$ single pulse; $t_p \leq 10\text{ }\mu\text{s}$              |     | -   | 12   | A    |
| $E_{DS(AL)S}$             | non-repetitive drain-source avalanche energy | $T_{j(\text{init})} = 25\text{ °C}; I_D = 1.3\text{ A};$ DUT in avalanche (unclamped) |     | -   | 6    | mJ   |
| $P_{tot}$                 | total power dissipation                      | $T_{amb} = 25\text{ °C}$  | [2] | -   | 460  | mW   |
|                           |  |   | [1] | -   | 1.1  | W    |
|                           |  | $T_{sp} = 25\text{ °C}$   |     | -   | 4.5  | W    |
| $T_j$                     | junction temperature                         |   |     | -55 | 150  | °C   |
| $T_{amb}$                 | ambient temperature                          |   |     | -55 | 150  | °C   |
| $T_{stg}$                 | storage temperature                          |   |     | -65 | 150  | °C   |
| <b>Source-drain diode</b> |  |   |     |     |      |      |
| $I_S$                     | source current                               | $T_{amb} = 25\text{ °C}$  | [1] | -   | 1    | A    |
| <b>ESD maximum rating</b> |  |   |     |     |      |      |
| $V_{ESD}$                 | electrostatic discharge voltage              | HBM   | [3] | -   | 2000 | V    |

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain  $6\text{ cm}^2$ .

[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[3] Measured between all pins.



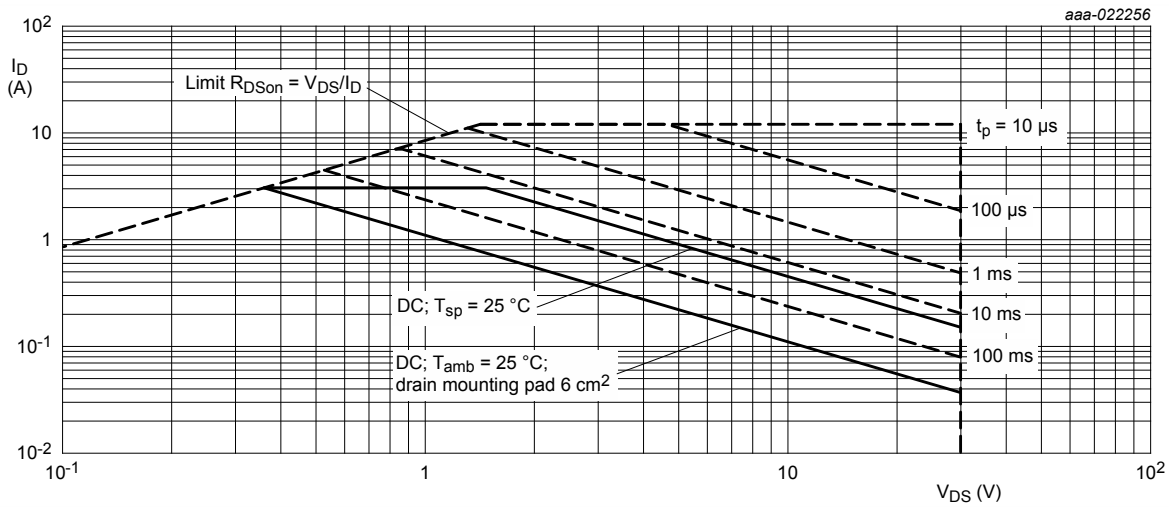
**Fig. 1. Normalized total power dissipation as a function of junction temperature**

$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \%$$



**Fig. 2. Normalized continuous drain current as a function of junction temperature**

$$I_{der} = \frac{I_D}{I_{D(25^{\circ}C)}} \times 100 \%$$



**Fig. 3. Safe operating area; junction to ambient; continuous and peak drain currents as a function of drain-source voltage**

### 9. Thermal characteristics

Table 6. Thermal characteristics

| Symbol         | Parameter  | Conditions  |     | Min | Typ | Max | Unit |
|----------------|--|-------------|-----|-----|-----|-----|------|
| $R_{th(j-a)}$  | thermal resistance from junction to ambient      | in free air | [1] | -   | 227 | 270 | K/W  |
|                |  |             | [2] | -   | 99  | 115 | K/W  |
| $R_{th(j-sp)}$ | thermal resistance from junction to solder point |             |     | -   | 20  | 28  | K/W  |

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm<sup>2</sup>.

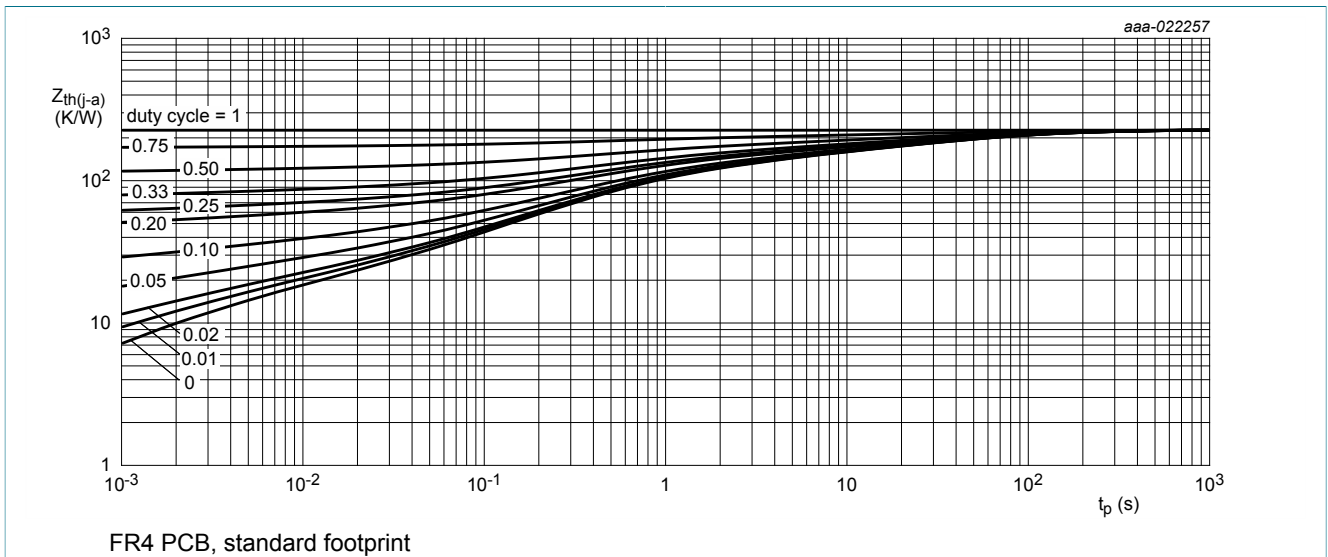


Fig. 4. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

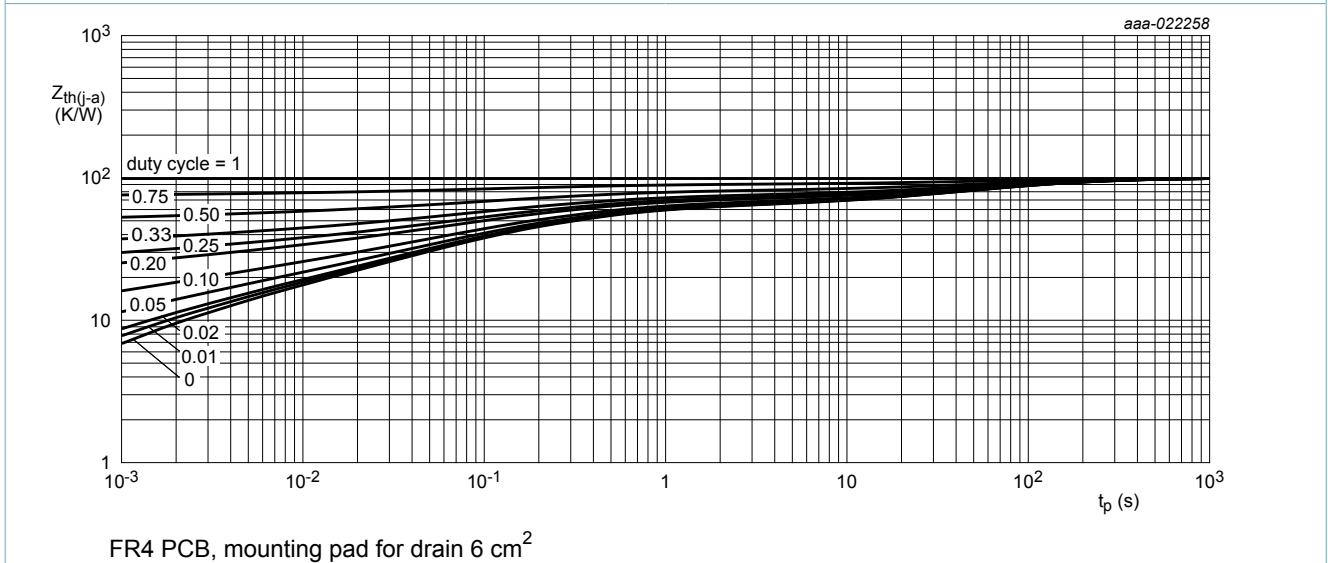
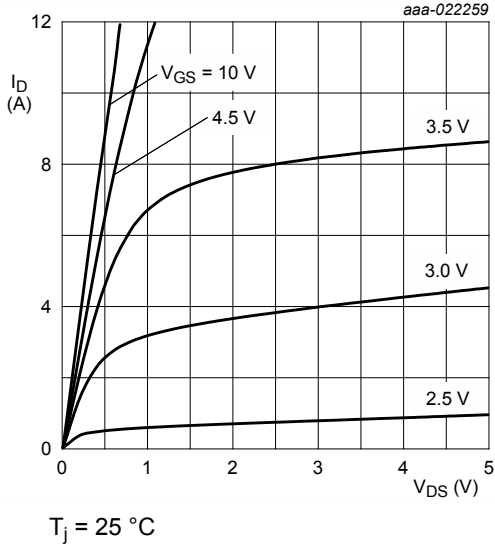


Fig. 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

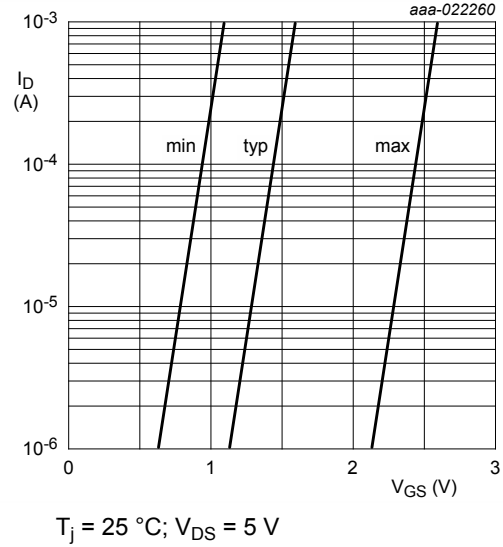
## 10. Characteristics

Table 7. Characteristics

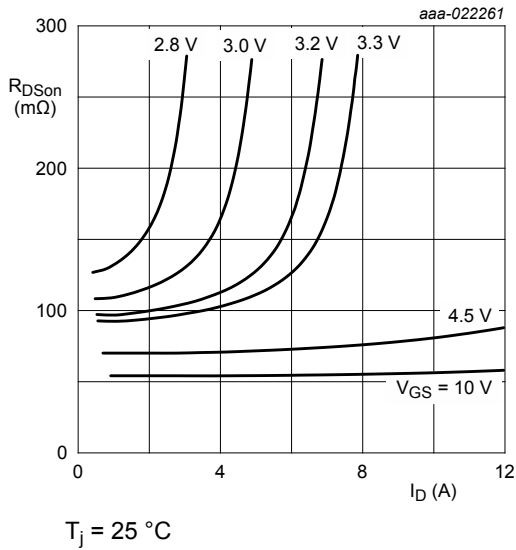
| Symbol                         | Parameter                        | Conditions   | Min  | Typ  | Max | Unit          |
|--------------------------------|----------------------------------|--|--|------|-----|---------------|
| <b>Static characteristics</b>  |                                  |  |  |      |     |               |
| $V_{(BR)DSS}$                  | drain-source breakdown voltage   | $I_D = 250 \mu\text{A}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ }^\circ\text{C}$                     | 30   | -    | -   | V             |
| $V_{GSth}$                     | gate-source threshold voltage    | $I_D = 250 \mu\text{A}; V_{DS} = V_{GS}; T_j = 25 \text{ }^\circ\text{C}$                          | 1  | 1.5  | 2.5 | V             |
| $I_{DSS}$                      | drain leakage current            | $V_{DS} = 30 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ }^\circ\text{C}$                     | -  | -    | 1   | $\mu\text{A}$ |
| $I_{GSS}$                      | gate leakage current             | $V_{GS} = 20 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ }^\circ\text{C}$                     | -  | -    | 10  | $\mu\text{A}$ |
|                                |                                  | $V_{GS} = -20 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ }^\circ\text{C}$                    | -  | -    | -10 | $\mu\text{A}$ |
|                                |                                  | $V_{GS} = 10 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ }^\circ\text{C}$                     | -  | -    | 2   | $\mu\text{A}$ |
|                                |                                  | $V_{GS} = -10 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ }^\circ\text{C}$                    | -  | -    | -2  | $\mu\text{A}$ |
| $R_{DSon}$                     | drain-source on-state resistance | $V_{GS} = 10 \text{ V}; I_D = 3 \text{ A}; T_j = 25 \text{ }^\circ\text{C}$                        | -  | 54   | 72  | m $\Omega$    |
|                                |                                  | $V_{GS} = 10 \text{ V}; I_D = 3 \text{ A}; T_j = 150 \text{ }^\circ\text{C}$                       | -  | 88   | 118 | m $\Omega$    |
|                                |                                  | $V_{GS} = 4.5 \text{ V}; I_D = 2.6 \text{ A}; T_j = 25 \text{ }^\circ\text{C}$                     | -  | 70   | 100 | m $\Omega$    |
| $g_{fs}$                       | forward transconductance         | $V_{DS} = 10 \text{ V}; I_D = 3 \text{ A}; T_j = 25 \text{ }^\circ\text{C}$                        | -  | 9    | -   | S             |
| $R_G$                          | gate resistance                  | $f = 1 \text{ MHz}$  | -  | 11.5 | -   | $\Omega$      |
| <b>Dynamic characteristics</b> |                                  |  |  |      |     |               |
| $Q_{G(tot)}$                   | total gate charge                | $V_{DS} = 15 \text{ V}; I_D = 3 \text{ A}; V_{GS} = 10 \text{ V}; T_j = 25 \text{ }^\circ\text{C}$ | -  | 3.6  | 5.5 | nC            |
| $Q_{GS}$                       | gate-source charge               |  | -  | 0.4  | -   | nC            |
| $Q_{GD}$                       | gate-drain charge                |  | -  | 0.7  | -   | nC            |
| $C_{iss}$                      | input capacitance                | $V_{DS} = 15 \text{ V}; f = 1 \text{ MHz}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ }^\circ\text{C}$  | -  | 160  | -   | pF            |
| $C_{oss}$                      | output capacitance               |  | -  | 33   | -   | pF            |
| $C_{riss}$                     | reverse transfer capacitance     |  | -  | 26   | -   | pF            |
| $t_{d(on)}$                    | turn-on delay time               |  | $V_{DS} = 15 \text{ V}; I_D = 3 \text{ A}; V_{GS} = 10 \text{ V}; R_{G(ext)} = 6 \text{ } \Omega; T_j = 25 \text{ }^\circ\text{C}$ | -    | 6   | -             |
| $t_r$                          | rise time                        | -  |  | 6    | -   | ns            |
| $t_{d(off)}$                   | turn-off delay time              | -  |  | 11   | -   | ns            |
| $t_f$                          | fall time                        | -  |  | 4    | -   | ns            |
| <b>Source-drain diode</b>      |                                  |  |  |      |     |               |
| $V_{SD}$                       | source-drain voltage             | $I_S = 1 \text{ A}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ }^\circ\text{C}$                         | -  | 0.8  | 1.2 | V             |



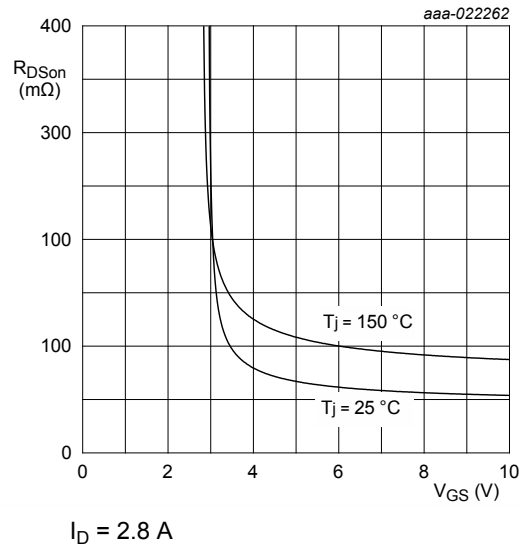
**Fig. 6. Output characteristics: drain current as a function of drain-source voltage; typical values**



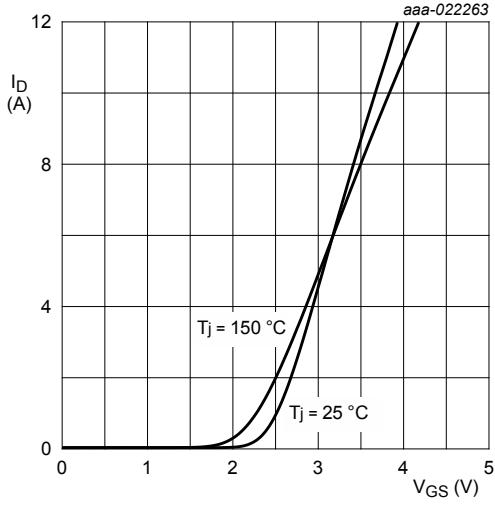
**Fig. 7. Sub-threshold drain current as a function of gate-source voltage**



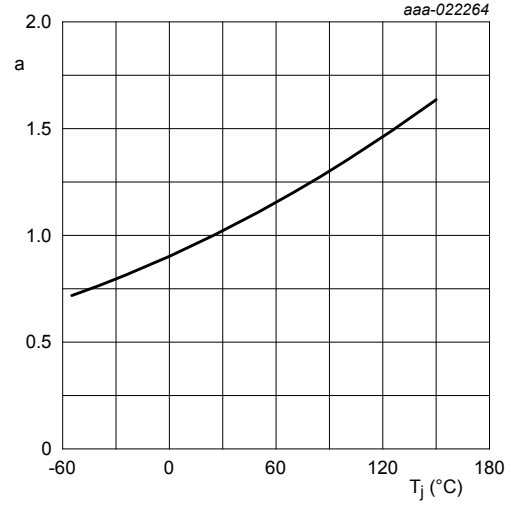
**Fig. 8. Drain-source on-state resistance as a function of drain current; typical values**



**Fig. 9. Drain-source on-state resistance as a function of gate-source voltage; typical values**

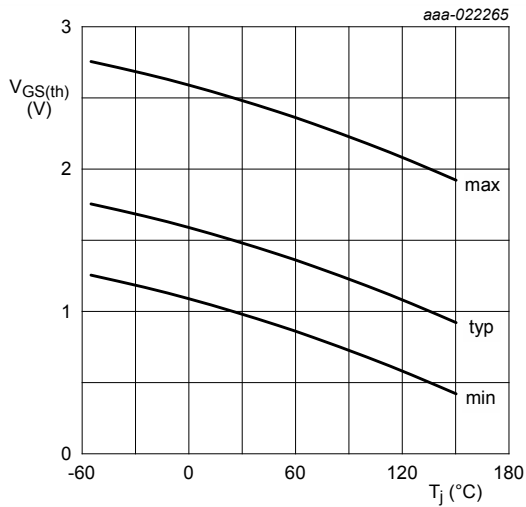


**Fig. 10. Transfer characteristics: drain current as a function of gate-source voltage; typical values**



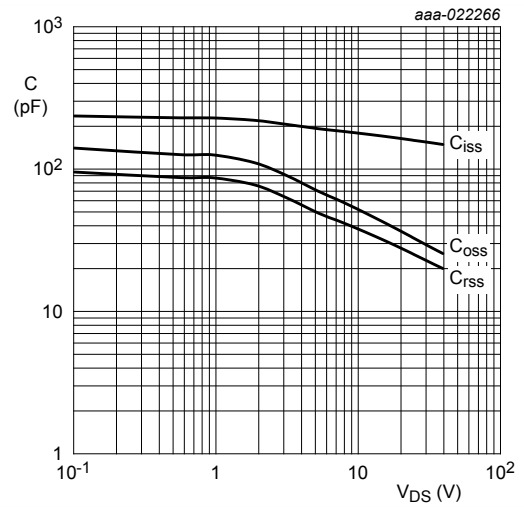
**Fig. 11. Normalized drain-source on-state resistance as a function of junction temperature; typical values**

$$a = \frac{R_{DSon}}{R_{DSon(25^{\circ}C)}}$$



**Fig. 12. Gate-source threshold voltage as a function of junction temperature**

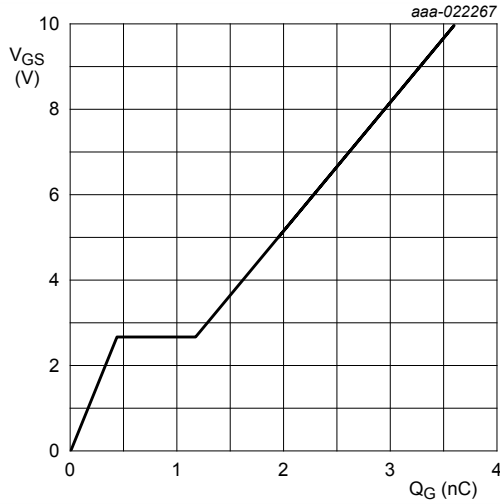
$I_D = 0.25 \text{ mA}; V_{DS} = V_{GS}$



**Fig. 13. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values**

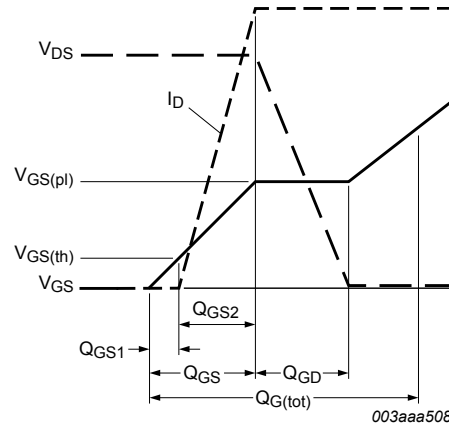
$f = 1 \text{ MHz}; V_{GS} = 0 \text{ V}$



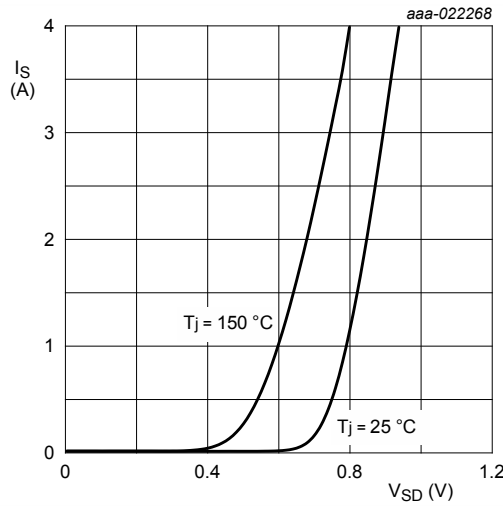


$I_D = 3 \text{ A}$ ;  $V_{DS} = 15 \text{ V}$ ;  $T_{amb} = 25 \text{ }^\circ\text{C}$

**Fig. 14. Gate-source voltage as a function of gate charge; typical values**



**Fig. 15. MOSFET transistor: Gate charge waveform definitions**



$V_{GS} = 0 \text{ V}$

**Fig. 16. Source current as a function of source-drain voltage; typical values**

## 11. Test information

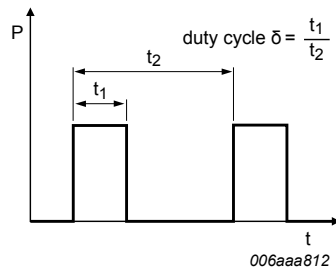


Fig. 17. Duty cycle definition

### 11.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

## 12. Package outline



Fig. 18. Package outline TO-236AB (SOT23)

### 13. Soldering



Fig. 19. Reflow soldering footprint for TO-236AB (SOT23)



Fig. 20. Wave soldering footprint for TO-236AB (SOT23)

## 14. Revision history

Table 8. Revision history

| Data sheet ID  | Release date | Data sheet status  | Change notice | Supersedes |
|----------------|--------------|--------------------|---------------|------------|
| PMV100ENEA v.1 | 20160317     | Product data sheet | -             | -          |

## 15. Legal information

### 15.1 Data sheet status

| Document status [1][2]         | Product status [3] | Definition  |
|--------------------------------|--------------------|---|
| Objective [short] data sheet   | Development        | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification      | This document contains data from the preliminary specification.                       |
| Product [short] data sheet     | Production         | This document contains the product specification.                                     |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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